# NSN 5961-01-333-7713

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-7713

# **Inclosure Material:**

Ceramic and metal

# **Overall Length:**

Between 0.970 inches and 0.990 inches

# **Overall Height:**

0.310 inches

#### **Overall Width:**

0.810 inches

#### **End Application:**

5865-01-219-2097 jamming system, communications, general utility

# Mounting Facility Quantity:

2

# Internal Configuration:

Field effect

#### **Mounting Method:**

#### Unthreaded hole

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage

# **Current Rating Per Characteristic:**

6.00 amperes drain current

# Power Rating Per Characteristic:

120.0 watts total device dissipation

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

3 ribbon

#### Shelf Life:

N/a

#### Unit Of Measure:

```
---
```

# Demilitarization:

No

#### Fiig:

A110a0